NSN 5961-01-484-1729

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-484-1729 **Inclosure Material:** Plastic **Overall Length:** 2.285 inches **Overall Diameter:** 0.050 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 repetitive peak reverse voltage and 0.55 forward voltage, dc and 28.0 reverse voltage, total rms **Current Rating Per Characteristic:** 5.00 amperes forward current, average and 150.00 amperes forward current, average preset **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No